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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:)	
)	
Singh et al.)	Group Art Unit: 2811
)	
Application No. 10/633,021)	Examiner: Vu, Hung K.
)	
Filed: 07/31/2003)	Date: 09/05/2006
)	
For: PAD OVER ACTIVE CIRCUIT)	
SYSTEM AND METHOD WITH)	
FRAME SUPPORT STRUCTURE)	

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

ATTENTION: Board of Patent Appeals and Interferences

APPEAL BRIEF (37 C.F.R. § 41.37)

This brief is in furtherance of the Notice of Appeal filed in this case on 06/20/2006, and the Notice of Panel Decision from Pre-Appeal Brief Review mailed 08/02/06.

The fees required under § 1.17, and any required petition for extension of time for filing this brief and fees therefor, are dealt with in the accompanying TRANSMITTAL OF APPEAL BRIEF.

This brief contains these items under the following headings, and in the order set forth below (37 C.F.R. § 41.37(c)(i)):

- I REAL PARTY IN INTEREST
- II RELATED APPEALS AND INTERFERENCES
- III STATUS OF CLAIMS
- IV STATUS OF AMENDMENTS
- V SUMMARY OF CLAIMED SUBJECT MATTER
- VI GROUNDS OF REJECTION TO BE REVIEWED ON APPEAL

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Date: September 5, 2006	Phone Number	Fax Number
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From: Kevin J. Zilka		

Docket No.: NVIDP235/P000846

App. No: 10/633,021

Total Number of Pages Being Transmitted, Including Cover Sheet: 28

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Kevin J. Zilka

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Practitioner's Docket No. NVIDP235/P000846

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Inderjit Singh et al.

Application No.: 10/633,021

Group No.: 2811

Filed: 07/31/2003

Examiner: Vu, H.

For: PAD OVER ACTIVE CIRCUIT SYSTEM AND METHOD WITH FRAME SUPPORT
STRUCTUREMail Stop Appeal Briefs - Patents
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450TRANSMITTAL OF APPEAL BRIEF
(PATENT APPLICATION-37 C.F.R. § 41.37)

1. Transmitted herewith, is the APPEAL BRIEF in this application, with respect to the Notice of Appeal filed on 06/20/2006, and the Notice of Panel Decision from Pre-Appeal Brief Review mailed 08/02/06.

2. STATUS OF APPLICANT

This application is on behalf of other than a small entity.

CERTIFICATION UNDER 37 C.F.R. §§ 1.8(a) and 1.10*

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Express Mail certification is optional.)

I hereby certify that, on the date shown below, this correspondence is being:

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09/05/2006

Date: _____

Erica L. Farlow

(type or print name of person certifying)

* Only the date of filing (' 1.6) will be the date used in a patent term adjustment calculation, although the date on any certificate of mailing or transmission under ' 1.8 continues to be taken into account in determining timeliness. See ' 1.703(f). Consider "Express Mail Post Office to Addressee" (' 1.10) or facsimile transmission (' 1.6(d)) for the reply to be accorded the earliest possible filing date for patent term adjustment calculations

Transmittal of Appeal Brief--page 1 of 2

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3. FEE FOR FILING APPEAL BRIEF

Pursuant to 37 C.F.R. § 41.20(b)(2), the fee for filing the Appeal Brief is:

other than a small entity \$500.00

Appeal Brief fee due \$500.00

4. EXTENSION OF TERM

The proceedings herein are for a patent application and the provisions of 37 C.F.R. § 1.136 apply.

Applicant believes that no extension of term is required. However, this conditional petition is being made to provide for the possibility that applicant has inadvertently overlooked the need for a petition and fee for extension of time.

5. TOTAL FEE DUE

The total fee due is:

Appeal brief fee \$500.00
Extension fee (if any) \$0.00

TOTAL FEE DUE \$500.00

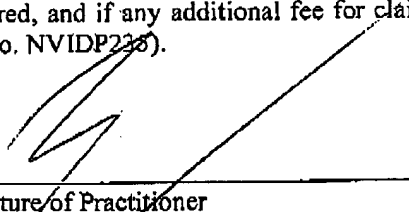
6. FEE PAYMENT

Authorization is hereby made to charge the amount of \$500.00 to Deposit Account No. 50-1351 (Order No. NVIDP235).

A duplicate of this transmittal is attached.

7. FEE DEFICIENCY

If any additional extension and/or fee is required, and if any additional fee for claims is required, charge Deposit Account No. 50-1351 (Order No. NVIDP235).

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Signature of Practitioner
Kevin J. Zilka
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USA

Transmittal of Appeal Brief—page 2 of 2

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- VII ARGUMENT
- VIII CLAIMS APPENDIX
- IX EVIDENCE APPENDIX
- X RELATED PROCEEDING APPENDIX

The final page of this brief bears the practitioner's signature.

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I REAL PARTY IN INTEREST (37 C.F.R. § 41.37(c)(1)(i))

The real party in interest in this appeal is NVIDIA Corporation.

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II RELATED APPEALS AND INTERFERENCES (37 C.F.R. § 41.37(c) (1)(ii))

With respect to other prior or pending appeals, interferences, or related judicial proceedings that will directly affect, or be directly affected by, or have a bearing on the Board's decision in the pending appeal, an appeal noted on 06/19/2006 in application serial number 10/633,004, and an appeal noted on 06/19/2006 in application serial number 11/067,551 may be, but are not necessarily, related.

Since no decision(s) has been rendered in such proceeding(s), no Related Proceedings Appendix is appended hereto.

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III STATUS OF CLAIMS (37 C.F.R. § 41.37(c) (1)(iii))

A. TOTAL NUMBER OF CLAIMS IN APPLICATION

Claims in the application are: 1, 2, 4-14, 16-18, 24, 26-27, and 29-30

B. STATUS OF ALL THE CLAIMS IN APPLICATION

1. Claims withdrawn from consideration: None
2. Claims pending: 1, 2, 4-14, 16-18, 24, 26-27, and 29-30
3. Claims allowed: None
4. Claims rejected: 1, 2, 4-14, 16-18, 24, 26-27, and 29-30
5. Claims cancelled: 3, 15, 19-23, 25, and 28

C. CLAIMS ON APPEAL

The claims on appeal are: 1, 2, 4-14, 16-18, 24, 26-27, and 29-30

See additional status information in the Appendix of Claims.

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IV STATUS OF AMENDMENTS (37 C.F.R. § 41.37(c)(1)(iv))

As to the status of any amendment filed subsequent to final rejection, there are no such amendments after final.

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V SUMMARY OF CLAIMED SUBJECT MATTER (37 C.F.R. § 41.37(c)(1)(v))

With respect to a summary of Claim 1, as shown in Figures 1-11, an integrated circuit (e.g. see item 300 of Figure 3, etc.) comprises an active circuit (e.g. see item 308 of Figure 3, etc.). See, for example, page 7, lines 4-11 et al. Further, a metal layer is disposed, at least partially, above the active circuit and a bond pad (e.g. see item 306 of Figure 3, etc.) is disposed, at least partially, above the metal layer. See, for example, page 7, lines 13-17 et al. Additionally, the metal layer defines a frame. See, for example, page 8, line 24 – page 9, line 2 et al. The metal layer (e.g. see item 412 of Figure 4, etc.) is disposed, at least partially, directly above the active circuit. See, for example, page 8, lines 11-18 et al. In addition, the frame ensures that bonds are capable of being placed over the active circuit without damage thereto during a bonding process. See, for example, page 15, lines 11-17 et al. Also, the active circuit includes a plurality of transistors. See, for example, page 3, lines 10-11 et al. An entirety of at least one of the transistors is disposed directly below the bond pad (e.g. see item 306 of Figure 3, etc.). See, for example, page 8, line 24 – page 9, line 2 et al. The frame ensures that at least one of the bonds is capable of being placed over the at least one transistor without damage thereto during the bonding process. See, for example, page 15, lines 11-17 et al.

With respect to a summary of Claim 16, as shown in Figures 1-11, an integrated circuit (e.g. see item 300 of Figure 3, etc.) comprises an active circuit means (e.g. see item 308 of Figure 3, etc.) for processing electrical signals. See, for example, page 7, lines 4-11 et al. A metal layer (e.g. see item 412 of Figure 4, etc.) is disposed, at least partially, above the active circuit means (e.g. see item 308 of Figure 3, etc.) and includes a frame means (e.g. see item 804 of Figure 8A, etc.) for preventing damage incurred during a bonding process. See, for example, page 15, lines 11-17 et al. A bond pad is disposed, at least partially, above the metal layer. The metal layer is disposed, at least partially, directly above the active circuit means (e.g. see item 308 of Figure 3, etc.). See, for example, page 8, lines 11-18 et al. In addition, the frame means (e.g. see item 804 of Figure 8A, etc.) ensures that bonds are capable of being placed over the active circuit means (e.g. see item 308 of Figure 3, etc.) without damage thereto during a bonding process. See, for example, page 15, lines 11-17 et al. Further, the active circuit means (e.g. see item 308 of Figure 3, etc.) includes a plurality of transistors. See, for example, page 3, lines 10-11 et al. An entirety

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of at least one of the transistors is disposed directly below the bond pad (e.g. see item 306 of Figure 3, etc.). See, for example, page 8, line 24 – page 9, line 2 et al. The frame means (e.g. see item 804 of Figure 8A, etc.) ensures that at least one of the bonds is capable of being placed over the at least one transistor without damage thereto during the bonding process. See, for example, page 15, lines 11-17 et al.

With respect to a summary of Claim 17, as shown in Figures 1-11, an integrated circuit (e.g. see item 300 of Figure 3, etc.) comprises a semiconductor structure including an active circuit (e.g. see item 308 of Figure 3, etc.) including an input/output (I/O) bus (e.g. see item 304 of Figure 3, etc.) and a plurality of transistors forming a core of circuits (e.g. see item 302 of Figure 3, etc.). A plurality of vertically spaced underlying metal layers (e.g. see item 406 of Figure 4, etc.) are disposed, at least partially, under the active circuit and around a periphery thereof. See, for example, page 8, lines 1-9 et al. Each of the underlying metal layers are in electrical communication by way of a plurality of underlying vias (e.g. see item 408 of Figure 4, etc.) with the active circuit and other underlying metal layers. Further, an interconnect metal layer is disposed, at least partially, above the I/O bus of the active circuit and around a periphery thereof. See, for example, page 9, lines 14-17 et al. The interconnect metal layer (e.g. see item 412 of Figure 4, etc.) is in electrical communication with the underlying metal layers (e.g. see item 406 of Figure 4, etc.) by way of a plurality of additional vias. See, for example, page 8, lines 11-18 et al. The interconnect metal layer defines a frame with an outer periphery and an inner periphery. In addition, an inter-metal dielectric layer is disposed, at least partially, above the interconnect metal layer. See, for example, page 8, lines 11-18 et al. The inter-metal dielectric layer (e.g. see item 416 of Figure 4, etc.) constructed from a material selected from the group consisting of a low-K dielectric material and a fluorinated silica glass (FSG) material. See, for example, page 8, lines 11-18 et al. Additionally, a top metal layer is disposed, at least partially, above the inter-metal dielectric layer, the top metal layer for serving as a bond pad (e.g. see item 306 of Figure 3, etc.), the top metal layer being in electrical communication with the interconnect metal layer by way of a plurality of interconnect vias. See, for example, page 8, line 20 – page 9, line 2 et al. Also, a passivation layer (e.g. see item 510 of Figure 5, etc.) is disposed, at least partially, above the top metal layer. See, for example, page 9, lines 14-21 et al. The metal layer is disposed, at least partially, directly above the active circuit. See, for example, page 9, lines 23-25 et al. Further, the frame ensures that bonds are capable of being placed over the active circuit

without damage thereto during a bonding process. See, for example, page 15, lines 11-17 et al. Also, an entirety of at least one of the transistors is disposed directly below the bond pad. See, for example, page 8, line 20 – page 9, line 2 et al. The frame ensures that at least one of the bonds is capable of being placed over the at least one transistor without damage thereto during the bonding process. See, for example, page 15, lines 11-17 et al.

With respect to a summary of Claim 18, as shown in Figures 1-11, an integrated circuit (e.g. see item 300 of Figure 3, etc.) comprises an active circuit (e.g. see item 308 of Figure 3, etc.). See, for example, page 7, lines 4-11 et al. Further, a metal layer is disposed, at least partially, above the active circuit. See, for example, page 9, lines 14-17 et al. The metal layer defines a substantially enclosed, rectangular frame (e.g. see item 804 of Figure 8A, etc.) with an outer periphery and an inner periphery. See, for example, page 13, lines 10-13 et al. In addition, a dielectric layer (e.g. see item 416 of Figure 4, etc.) is disposed, at least partially, above the metal layer. See, for example, page 8, lines 11-18 et al. Additionally, a bond pad is disposed, at least partially, above the metal layer (e.g. see item 412 of Figure 4, etc.). A plurality of vias (e.g. see item 408 of Figure 4, etc.) are formed along the frame for electrical communication between the metal layer and the bond pad (e.g. see item 306 of Figure 3, etc.). The metal layer is disposed, at least partially, directly above the active circuit. Further, the frame ensures that bonds are capable of being placed over the active circuit without damage thereto during a bonding process. See, for example, page 15, lines 11-17 et al. The active circuit includes a plurality of transistors. See, for example, page 3, lines 10-11 et al. An entirety of at least one of the transistors is disposed directly below the bond pad. See, for example, page 8, line 20 – page 9, line 2 et al. The frame ensures that at least one of the bonds is capable of being placed over the at least one transistor without damage thereto during the bonding process. See, for example, page 15, lines 11-17 et al.

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**VI GROUNDS OF REJECTION TO BE REVIEWED ON APPEAL (37 C.F.R. §
41.37(c)(1)(vi))**

Following, under each issue listed, is a concise statement setting forth the corresponding ground of rejection.

Issue # 1: The Examiner has rejected Claims 1, 2, 4-18, 20, 21, 27, 29 and 30 under 35 U.S.C. 112, first paragraph, as failing to comply with the written description requirement.

Issue # 2: The Examiner has rejected Claims 1, 4-14, 16, 18, 24, 26-27, and 29-30 under 35 U.S.C. 103(a) as being unpatentable over Suzuki et al. (U.S. Patent Number: 6,707,156) in view of Tanaka (U.S. Patent Number: 6,100,589).

Issue # 3: The Examiner has rejected Claims 2, and 17 under 35 U.S.C. 103(a) as being unpatentable over Suzuki et al. (U.S. Patent Number: 6,707,156) in view of Tanaka (U.S. Patent Number: 6,100,589) in further view of Applicant's Admitted Prior Art of Figures 1-2.

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VII ARGUMENT (37 C.F.R. § 41.37(c)(1)(vii))

The claims of the groups noted below do not stand or fall together. In the present section, appellant explains why the claims of each group are believed to be separately patentable.

Issue # 1:

The Examiner has rejected Claims 1, 2, 4-18, 20, 21, 27, 29 and 30 under 35 U.S.C. 112, first paragraph, as failing to comply with the written description requirement.

Specifically, the Examiner argues that the specification does not disclose an entirety of at least one of the transistors being disposed directly below the bond pad, as recited in Claim 1, 20 and 21. On page 3, lines 10-11 of the originally filed application, it is disclosed that "the active circuit may include a plurality of transistors." Further, Claim 17 of the originally filed application discloses "a plurality of transistors forming a core of circuits." Still yet, on page of 7, lines 16-17 of the originally filed application, it is disclosed that "the bond pads 306 may be disposed above the core 302, and/or any other part of the active circuit 308." By virtue of this and other disclosure, appellant's claims clearly meet the written description requirement.

Issue # 2:

The Examiner has rejected Claims 1, 4-14, 16, 18, 24, 26-27, and 29-30 under 35 U.S.C. 103(a) as being unpatentable over Suzuki et al. (U.S. Patent Number: 6,707,156) in view of Tanaka (U.S. Patent Number: 6,100,589).

To establish a *prima facie* case of obviousness, three basic criteria must be met. First, there must be some suggestion or motivation, either in the references themselves or in the knowledge generally available to one of ordinary skill in the art, to modify the reference or to combine reference teachings. Second, there must be a reasonable expectation of success. Finally, the prior art reference (or references when combined) must teach or suggest all the claim limitations. The teaching or suggestion to make the claimed combination and the reasonable expectation of

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success must both be found in the prior art and not based on appellant's disclosure. *In re Vaeck*, 947 F.2d 488, 20 USPQ2d 1438 (Fed.Cir.1991).

With respect to the first element of the *prima facie* case of obviousness, the Examiner states that it would have been obvious to one of ordinary skill in the art at the time the invention was made to form the integrated circuit of Suzuki et al. having the metal layer defined a frame, such as taught by Tanaka in order to further improve the mechanical strength and to further enhance the effects for suppressing crack formation in the insulation interlayer so that it inherently prevents the damage to the active circuit and/or the at least one transistor during the bonding process. Appellant respectfully disagrees with this proposition, especially in view of the vast evidence to the contrary.

Specifically, it is noted that Tanaka merely addresses the problem of arranging bonding pads with high density, since a first electrode layer must have a large area in order to secure the bonding area, due to disconnection from bumps of aluminum wiring, etc. Note col. 1, lines 15-45 from Tanaka. Therefore, it is clear that Tanaka simply does not address the problem of bonding-related damage to the active circuit.

Still yet, it is noted that Suzuki does not even mention bonding, let alone the problem of bonding-related damage to the active circuit. Specifically, Suzuki merely teaches a technique for dealing with an increase of stress associated with increasing a height of a multilevel wiring layer structure. For example, Suzuki discloses that "if an interlayer insulating layer of SiOC is disposed between an organic insulating layer and a silicon oxide layer, the generation of stress and the like to be caused by a difference of a physical constant between the upper and lower level layers can be suppressed" (col. 6, lines 11-15). Thus, Suzuki simply does not even address the problem of bonding-related damage to the active circuit.

To this end, neither prior art references even teach the problem solved by appellant. See *Eibel Process Co. v Minnesota & Ontario Paper Co.*, 261 US 45 (1923). Therefore, for at least the reasons set forth hereinabove, the first element of the *prima facie* case of obviousness has simply not been met.

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More importantly, with respect to the third element of the *prima facie* case of obviousness, the Examiner relies on Figure 1 from Suzuki to make a prior art showing of appellant's claimed structure "wherein the [metal layer]... ensures that bonds are capable of being placed over the active circuit" (see this or similar, but not necessarily identical language in each of the independent claims).

Appellant respectfully disagrees with this assertion. First, as mentioned above, Suzuki does not even mention bonding, let alone the problem of bonding-related damage to the active circuit. Specifically, it is noted that Suzuki merely teaches a technique for dealing with an increase of stress associated with increasing a height of a multilevel wiring layer structure. For example, Suzuki discloses that "if an interlayer insulating layer of SiOC is disposed between an organic insulating layer and a silicon oxide layer, the generation of stress and the like to be caused by a difference of a physical constant between the upper and lower level layers can be suppressed" (col. 6, lines 11-15).

Such disclosure simply does not "ensure that bonds are capable of being placed over the active circuit," let alone "without damage thereto during a bonding process" (emphasis added), as claimed. It appears that the Examiner has admitted to not identifying the above emphasized claim language in the prior art. It also noted that the Examiner appears to rely on an inherency argument by arguing that the resultant combination *inherently* prevents the damage to the active circuit and/or the at least one transistor during the bonding process.

In response, appellant asserts that the fact that a certain result or characteristic may occur or be present in the prior art is not sufficient to establish the inherency of that result or characteristic. *In re Rijckaert*, 9 F.3d 1531, 1534, 28 USPQ2d 1955, 1957 (Fed. Cir. 1993); *In re Oelrich*, 666 F.2d 578, 581-82, 212 USPQ 323, 326 (CCPA 1981). "To establish inherency, the extrinsic evidence 'must make clear that the missing descriptive matter is necessarily present in the thing described in the reference, and that it would be so recognized by persons of ordinary skill. Inherency, however, may not be established by probabilities or possibilities. The mere fact that a certain thing may result from a given set of circumstances is not sufficient.'" *In re Robertson*, 169 F.3d 743, 745, 49 USPQ2d 1949, 1950-51 (Fed. Cir. 1999)

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Appellant respectfully asserts that the claimed "frame [which] ensures that bonds are capable of being placed over the active circuit without damage thereto during a bonding process" would be *unobvious* in view of the proposed prior art combination, since only appellant teaches and claims the novel use of such framed metal layer structure for the specific purpose of ensuring that bonds are capable of being placed over the active circuit without damage thereto during a bonding process, as claimed.

In summary, none of the references relied upon by the Examiner even suggest a frame, as claimed by appellant, to ensure that bonds are capable of being placed over the active circuit without damage thereto during a bonding process. For these reasons, appellant respectfully asserts that the third element of the *prima facie* case of obviousness has not been met, since the prior art references, when combined, fail to teach or suggest all of the claim limitations, as noted above.

Issue # 3:

The Examiner has rejected Claims 2, and 17 under 35 U.S.C. 103(a) as being unpatentable over Suzuki et al. (U.S. Patent Number: 6,707,156) in view of Tanaka (U.S. Patent Number: 6,100,589) in further view of Applicant's Admitted Prior Art of Figures 1-2.

Group #1 - Claim 2

Appellant respectfully asserts that such claims are not met by the prior art for the reasons argued with respect to Issue #2, Group #1.

Again, appellant respectfully asserts that at least the third element of the *prima facie* case of obviousness has not been met, since the prior art references, when combined, fail to teach or suggest all of the claim limitations, as noted above.

Group #2 - Claim 17

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VIII CLAIMS APPENDIX (37 C.F.R. § 41.37(c)(1)(viii))

The text of the claims involved in the appeal (along with associated status information) is set forth below:

1. (Previously Presented) An integrated circuit, comprising:
an active circuit;
a metal layer disposed, at least partially, above the active circuit; and
a bond pad disposed, at least partially, above the metal layer;
wherein the metal layer defines a frame;
wherein the metal layer is disposed, at least partially, directly above the active circuit;
wherein the frame ensures that bonds are capable of being placed over the active circuit without damage thereto during a bonding process;
wherein the active circuit includes a plurality of transistors, and an entirety of at least one of the transistors is disposed directly below the bond pad, and the frame ensures that at least one of the bonds is capable of being placed over the at least one transistor without damage thereto during the bonding process.
2. (Original) The integrated circuit as recited in claim 1, wherein the active circuit includes an input/output (I/O) bus.
3. (Cancelled)
4. (Original) The integrated circuit as recited in claim 1, wherein the metal layer includes an interconnect metal layer.
5. (Original) The integrated circuit as recited in claim 4, wherein the interconnect metal layer interconnects the bond pad with a plurality of underlying metal layers.
6. (Previously Presented) The integrated circuit as recited in claim 5, wherein each of the underlying metal layers is in electrical communication by way of a plurality of vias.

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7. (Original) The integrated circuit as recited in claim 1, wherein the frame defines an outer periphery and an inner periphery.
8. (Original) The integrated circuit as recited in claim 7, wherein the frame is enclosed.
9. (Original) The integrated circuit as recited in claim 7, wherein the metal layer defines an island formed within and spaced from the inner periphery of the frame of the metal layer.
10. (Original) The integrated circuit as recited in claim 9, wherein the island of the metal layer includes a plurality of openings formed therein.
11. (Original) The integrated circuit as recited in claim 10, wherein the openings are adapted for facilitating an interlock between the metal layer and an inter-metal dielectric layer disposed between the metal layer and the bond pad.
12. (Original) The integrated circuit as recited in claim 10, wherein the openings are completely enclosed around a periphery thereof.
13. (Original) The integrated circuit as recited in claim 10, wherein the openings have a substantially square configuration.
14. (Original) The integrated circuit as recited in claim 1, wherein a plurality of interconnect vias are formed along the frame.
15. (Cancelled)
16. (Previously Presented) An integrated circuit, comprising:
 - an active circuit means for processing electrical signals;
 - a metal layer disposed, at least partially, above the active circuit means and including a frame means for preventing damage incurred during a bonding process; and
 - a bond pad disposed, at least partially, above the metal layer;

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wherein the metal layer is disposed, at least partially, directly above the active circuit means;

wherein the frame means ensures that bonds are capable of being placed over the active circuit means without damage thereto during a bonding process;

wherein the active circuit means includes a plurality of transistors, and an entirety of at least one of the transistors is disposed directly below the bond pad, and the frame means ensures that at least one of the bonds is capable of being placed over the at least one transistor without damage thereto during the bonding process.

17. (Previously Presented) An integrated circuit, comprising:

a semiconductor structure including an active circuit including an input/output (I/O) bus and a plurality of transistors forming a core of circuits;

a plurality of vertically spaced underlying metal layers disposed, at least partially, under the active circuit and around a periphery thereof, wherein each of the underlying metal layers are in electrical communication by way of a plurality of underlying vias with the active circuit and other underlying metal layers;

an interconnect metal layer disposed, at least partially, above the I/O bus of the active circuit and around a periphery thereof, the interconnect metal layer being in electrical communication with the underlying metal layers by way of a plurality of additional vias, wherein the interconnect metal layer defines a frame with an outer periphery and an inner periphery;

an inter-metal dielectric layer disposed, at least partially, above the interconnect metal layer, the inter-metal dielectric layer constructed from a material selected from the group consisting of a low-K dielectric material and a fluorinated silica glass (FSG) material;

a top metal layer disposed, at least partially, above the inter-metal dielectric layer, the top metal layer for serving as a bond pad, the top metal layer being in electrical communication with the interconnect metal layer by way of a plurality of interconnect vias; and

a passivation layer disposed, at least partially, above the top metal layer;

wherein the metal layer is disposed, at least partially, directly above the active circuit;

wherein the frame ensures that bonds are capable of being placed over the active circuit without damage thereto during a bonding process;

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wherein an entirety of at least one of the transistors is disposed directly below the bond pad, and the frame ensures that at least one of the bonds is capable of being placed over the at least one transistor without damage thereto during the bonding process.

18. (Previously Presented) An integrated circuit, comprising:

an active circuit;

a metal layer disposed, at least partially, above the active circuit, the metal layer defining a substantially enclosed, rectangular frame with an outer periphery and an inner periphery;

a dielectric layer disposed, at least partially, above the metal layer; and

a bond pad disposed, at least partially, above the metal layer;

wherein a plurality of vias are formed along the frame for electrical communication between the metal layer and the bond pad;

wherein the metal layer is disposed, at least partially, directly above the active circuit;

wherein the frame ensures that bonds are capable of being placed over the active circuit without damage thereto during a bonding process;

wherein the active circuit includes a plurality of transistors, and an entirety of at least one of the transistors is disposed directly below the bond pad, and the frame ensures that at least one of the bonds is capable of being placed over the at least one transistor without damage thereto during the bonding process.

19. (Cancelled)

20. (Cancelled)

21. (Cancelled)

22. (Cancelled)

23. (Cancelled)

24. (Previously Presented) The integrated circuit as recited in claim 1, wherein the metal layer is disposed, at least partially, above the active circuit along a vertical axis.

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25. (Cancelled)

26. (Previously Presented) The integrated circuit as recited in claim 11, wherein the inter-metal dielectric layer is constructed from a low-K dielectric material.

27. (Previously Presented) The integrated circuit as recited in claim 11, wherein the inter-metal dielectric layer is constructed from a fluorinated silica glass (FSG) material.

28. (Cancelled)

29. (Previously Presented) The integrated circuit as recited in claim 9, wherein the island is spaced from the frame with a continuous, uninterrupted space therebetween.

30. (Previously Presented) The integrated circuit as recited in claim 7, wherein the inner periphery of the frame is continuous and defines a single, central rectangular space.

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IX EVIDENCE APPENDIX (37 C.F.R. § 41.37(c)(1)(ix))

There is no such evidence.

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X RELATED PROCEEDING APPENDIX (37 C.F.R. § 41.37(c)(1)(x))

Since no decision(s) has been rendered in such proceeding(s), no material is included in this Related Proceedings Appendix.

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In the event a telephone conversation would expedite the prosecution of this application, the Examiner may reach the undersigned at (408) 971-2573. For payment of any additional fees due in connection with the filing of this paper, the Commissioner is authorized to charge such fees to Deposit Account No. 50-1351 (Order No. NVIDP235/P000846).

Respectfully submitted,

By:  _____

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Reg. No. 41,429

Date: 9/5/06

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